

APPROVAL SHEET

Approval Specification Customer's Approval Certification	
TO:	Checked & Approved by:
Part No.:	Date:
Customer's Part No.:	Please return this copy as a
	certification of your approval

KaiTuo Crystal Technology (Zhongshan) Co., Ltd.

Tel: +86-760-22556637 Fax: +86-760-22556637

E-mail: sales@kt-saw.com QQ: 88210849 Website: http://www.kt-saw.com

Add: 3rd Floor, Block B, No. 8 Baocheng Road, Xiaolan Town, Zhongshan City

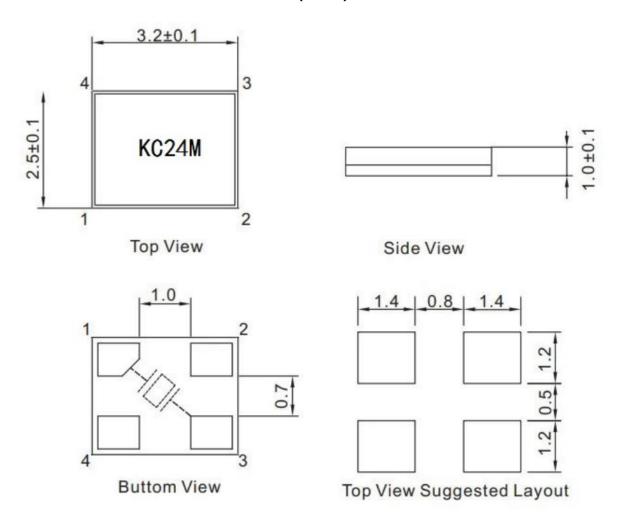
Part No.	:	KC24M
Pages	:	7
Date	:	2021/7/1
Revision	:	1.0

Repared by:	linle
Checked by:	55
Approved by:	166

History Record

Date	Part No.	Version No.	Modify Content	Remark

1.Product outline dimension(mm)



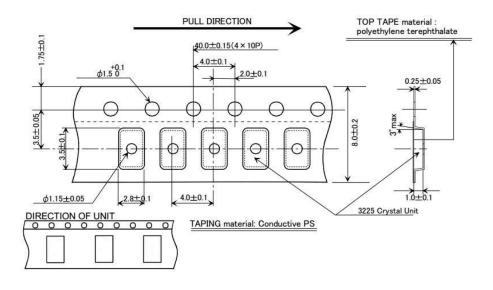
2. General characteristics

Nominal frequency	24.000000 MHz
Overtone order	Fundamental
Туре	MEMS3225
Operating temperature	-20~70 °C
Storage temperature	-40~85 °C

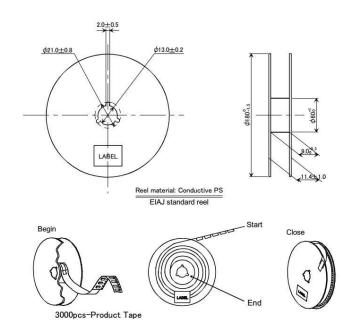
3. Electric characteristics

Adjustment tolerance: (at+25°C)	±10 ppm	
Load capacitance	12.0 pF	
Drive level	100.0 μW	
Equivalent resistance	60.0ΩMax	
Shut capacitance	3.0pF Max	
Aging	±3ppm/Year	

4. Carrier Dimensional Drawing (mm)



5.Reel Dimensional Drawing (mm)



6.Product reliability

1		
	Cold resistance	
	Stored at -40±2°C for 1000±2 hrs then 25±2°C 1~2 hrs before testing	(I)
2	Heat resistance	
	Stored at 85±2°C for 1000±2 hrs then 25±2°C 1~2 hrs before testing	(I)
3	Salt Mist Test	
	Spray the 35°C±2°C salt water (salt density 5%) to crystal for 48±2hrs,then	(I)
	clean by water	
4	Humidity Resistance Result	(I)
	Steady temperature: 60±2°C;humidity: 90 ~ 95 % RH; time:500h	
5	Mechanical Shock	
	14700m/S2 0.5sec 5times in each of 6 direction	(I)
6	Aging	
	Stored at $85\pm3^{\circ}$ C for 720 ± 12 Hrs then $25\pm2^{\circ}$ C $1\sim2$ Hrs before testing	(I)
	Stored at 25±2℃ for 1±0.03 year	
7	Leakage	
	Fine leak: Helium leak test *JIS C 6701 10.6	(V)
	Temperature Cycle	
	-40°C ~ 85°C , Dewell 30Min , 100 cycles	
	260±5°C	
	ature	
8	0.07	(I)
	150±5℃	
	Tooling Cooling	
	H H H H H H H H H H H H H H H H H H H	
	Time 120sec 10sec	
	$ \leftarrow$ 10sec	

7. Mechanism characteristics

1	Drop Test		
	Device are dropped from a height of 100 cm onto 20mm		
	thickness stainless plate executing 3 times of random drops	(I)	
2	Resistance of Vibration		
	Frequency: $10\sim55$ Hz, amplitude(total excursion): 1.5 mm $\pm15\%$,3	<i>(</i> T)	
	direction (X,Y,Z) each 2 hr	(I)	
3	Resistance to soldering heat (Hand soldering method)		
	Temperature: 370~400°C; Time: 3~4sec;		
	Frequency : 2 times ; Soldering iron : 60W/Min	(I)	
4	Solderability	(11)	
	240±2°C , 3±0.5sec	(II)	
	Reflow)Resistance to soldering heat(Reflow) 260± 5°C ;10S ;2Times		
	Reflow		
	TEMP. (°C)		
	300— 10s MAX		
	260±5℃ 250— 230±5℃		
	1		
	200—		
5	180————————————————————————————————————	(I)	
	100— 90-120S	.,	
	50 —		
	TIME (sec)		
	TIME (Sec)		
	THVIE (Sec)		
	THVIE (SEC)		

Item Result NO. Specification Requirements

- 1. Frequency variation < ± 10 ppm ; Resistance variation < 5Ω or 15% of RR spec. ; select the bigger value.
- 2. The covering rate of Tin-plating is more than 95%.
- 3. There is no bubbles after the Crystal is dipped in the water Insulation Resistance: 500 M Ω Min 100VDC/±15VDC.
- 4. The Crystal is no crackle under the observation of 10 times Magnifier.
- 5. 1*10-9Pa.m³/s Max

NOTES

- 1. As a result of the particularity of inner structure of Crystal products, it easy to be breakdown by electrostatic, so we should pay attention to **ESD protect** in the test.
- 2. **Static voltage** between signal load and ground may cause deterioration and destruction of the component. Please avoid static voltage.
- 3. **Ultrasonic cleaning** may cause deterioration and destruction of the component. Please avoid ultrasonic

cleaning.

- 4. Only leads of component may **be soldered**. Please avoid soldering another part of component.
- 5. There is a close relationship between the device's performance and **matching network**. The specifications of this device are based on the test circuit shown above. L and C values may change

depending on board layout. Values shown are intended as a guide only.

单击下面可查看定价,库存,交付和生命周期等信息

>>Kaituo Crystal(开拓晶体)